

# N-Channel PowerTrench<sup>®</sup> SyncFET<sup>TM</sup> 30 V, 42 A, 3 m $\Omega$

### Features

- Max r<sub>DS(on)</sub> = 3.0 mΩ at V<sub>GS</sub> = 10 V, I<sub>D</sub> = 21 A
- Max  $r_{DS(on)}$  = 3.2 m $\Omega$  at V<sub>GS</sub> = 7 V, I<sub>D</sub> = 19 A
- Advanced Package and Silicon combination for low r<sub>DS(on)</sub> and high efficiency
- SyncFET Schottky Body Diode
- MSL1 robust package design
- 100% UIL tested
- RoHS Compliant

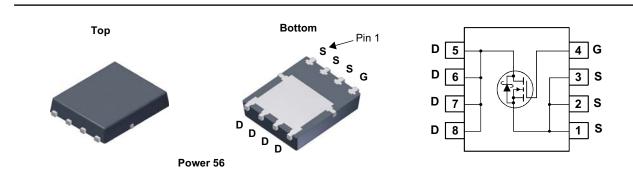


# **General Description**

The FDMS7670AS has been designed to minimize losses in power conversion application. Advancements in both silicon and package technologies have been combined to offer the lowest  $r_{DS(on)}$  while maintaining excellent switching performance. This device has the added benefit of an efficient monolithic Schottky body diode.

# Applications

- Synchronous Rectifier for DC/DC Converters
- Notebook Vcore/ GPU low side switch
- Networking Point of Load low side switch
- Telecom secondary side rectification



## MOSFET Maximum Ratings T<sub>C</sub> = 25 °C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V <sub>DS</sub>	Drain to Source Voltage			30	V
V <sub>GS</sub>	Gate to Source Voltage		(Note 4)	±20	V
	Drain Current -Continuous (Package limited) T <sub>C</sub> = 25 °C			42	
	-Continuous (Silicon limited) T <sub>C</sub>			113	
D	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	22	— A
	-Pulsed			150	
dv/dt	MOSFET dv/dt			1.8	V/ns
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	98	mJ
P <sub>D</sub>	Power Dissipation	T <sub>C</sub> = 25 °C	65		w
	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	2.5	VV
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C

### **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.9	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note	a) 50	C/VV

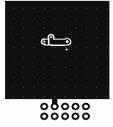
### Package Marking and Ordering Information

Γ	Device Marking	Device	Package	Reel Size	Tape Width	Quantity
	FDMS7670AS	FDMS7670AS	Power 56	13 "	12 mm	3000 units

October 2014

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N-Channel F
<b>V-Channel PowerTrench</b>
<sup>®</sup> SyncFET <sup>TM</sup>

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 1 mA, V <sub>GS</sub> = 0 V	30			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 10$ mA, referenced to 25 °C		14		mV/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 24 V, V <sub>GS</sub> = 0 V			500	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current, Forward	V <sub>GS</sub> = 20 V, V <sub>DS</sub> = 0 V			100	nA	
On Chara	cteristics (Note 2)						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 1 \text{ mA}$	1.2	1.6	3.0	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 10$ mA, referenced to 25 °C		-5		mV/°C	
	Static Drain to Source On Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 21 A		2.4	3.0		
-		V <sub>GS</sub> = 7 V, I <sub>D</sub> = 19 A		2.5	3.2	mΩ	
r <sub>DS(on)</sub>		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 17 A		3.0	3.5		
		$V_{GS}$ = 10 V, $I_D$ = 21 A, $T_J$ = 125 °C		3.0	3.8		
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 21 A		300		S	
Dynamic	Characteristics						
C <sub>iss</sub>	Input Capacitance	N 45.4.14 0.14		3175	4225	pF	
C <sub>oss</sub>	Output Capacitance	─ V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz		1175	1565	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance			110	165	pF	
R <sub>g</sub>	Gate Resistance			1.3	2.6	Ω	
Switching	g Characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time			14	25	ns	
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 21 A,		6	12	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		35	56	ns	
t <sub>f</sub>	Fall Time			5	10	ns	
Q <sub>g</sub>	Total Gate Charge	V <sub>GS</sub> = 0 V to 10 V		47	66	nC	
Q <sub>g</sub>	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V} \text{ V}_{DD} = 15 \text{ V},$		22	31	nC	
Q <sub>gs</sub>	Gate to Source Gate Charge	I <sub>D</sub> = 21 A		8.5		nC	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge	1 [		4.9		nC	
Drain-Sou	urce Diode Characteristics						
		V <sub>GS</sub> = 0 V, I <sub>S</sub> = 2 A (Note 2)		0.43	0.7		
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 21 A$ (Note 2)		0.75	1.2	V	
t <sub>rr</sub>	Reverse Recovery Time			35	56	ns	
Q <sub>rr</sub>	Reverse Recovery Charge	-I <sub>F</sub> = 21 A, di/dt = 300 A/ μs		41	67	nC	
Notes:		on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta,IC}$ is g					



a. 50 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.

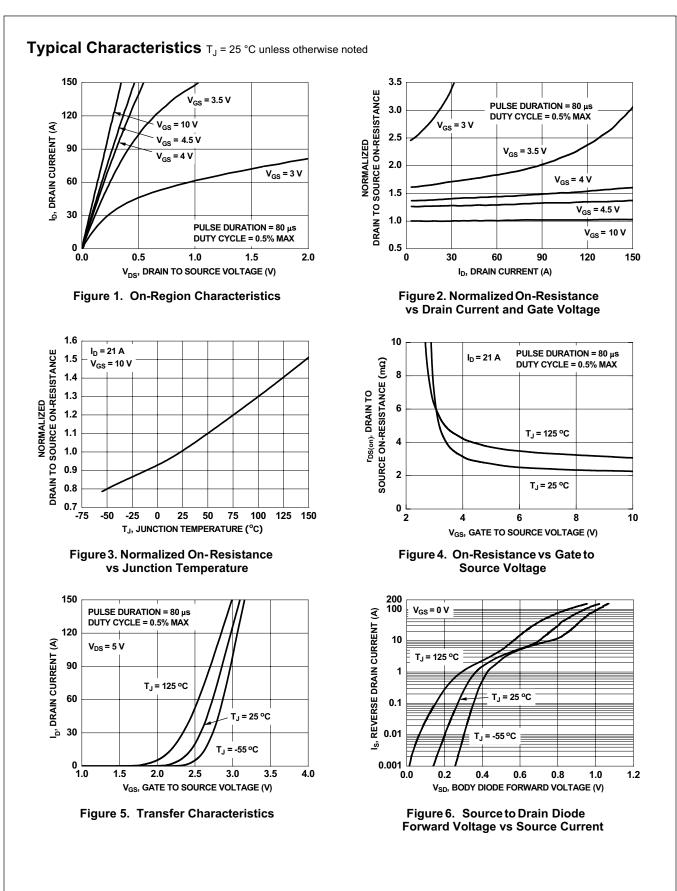
b. 125 °C/W when mounted on a minimum pad of 2 oz copper.

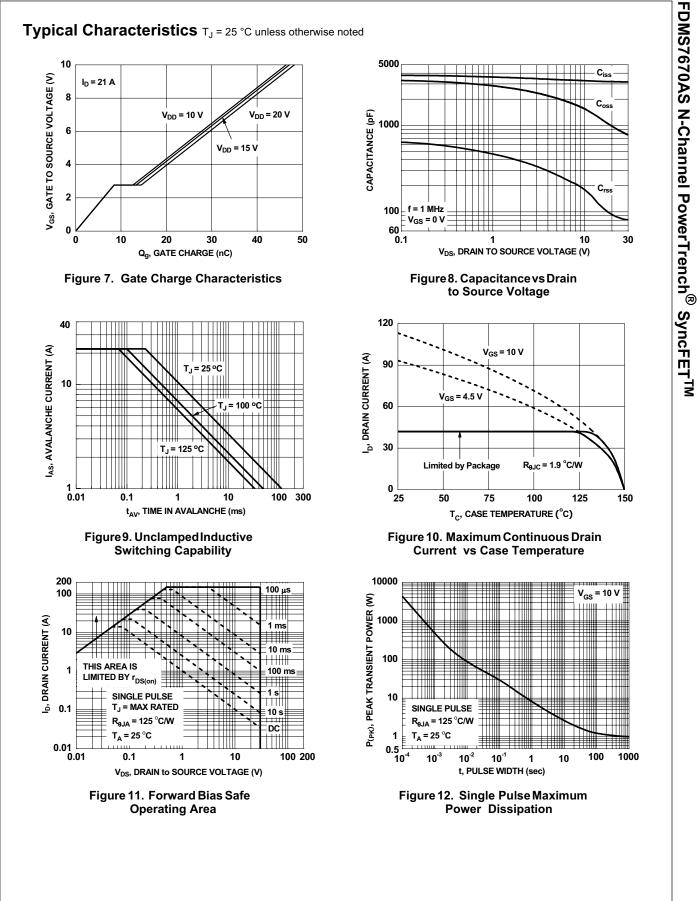


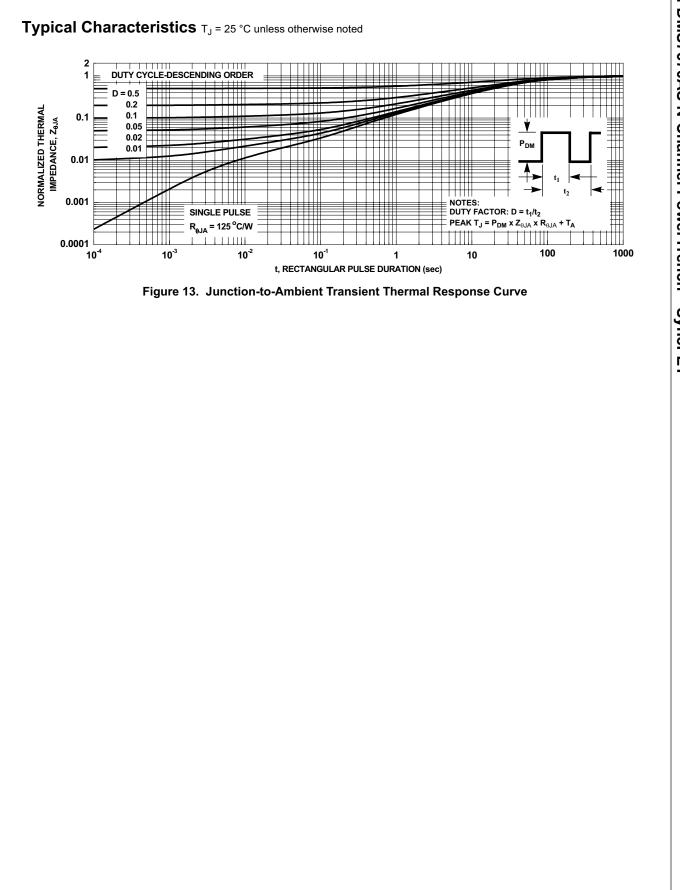
2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0%.

3.  $E_{AS}$  of 98 mJ is based on starting  $T_J$  = 25 °C, L = 1 mH,  $I_{AS}$  = 14 A,  $V_{DD}$  = 27 V,  $V_{GS}$  = 10 V. 100% test at L = 0.3 mH,  $I_{AS}$  = 21 A.

4. As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.







# FDMS7670AS N-Channel PowerTrench<sup>®</sup> SyncFET<sup>TM</sup>

## Typical Characteristics (continued)

### SyncFET Schottky body diode Characteristics

Fairchild's SyncFET process embeds a Schottky diode in parallel with PowerTrench MoSFET. This diode exhibits similar characteristics to a discrete external Schottky diode in parallel with a MOSFET. Figure 14 shows the reverses recovery characteristic of the FDMS7670AS.

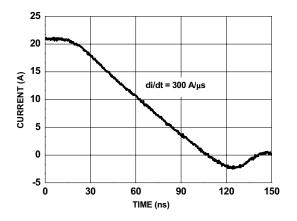
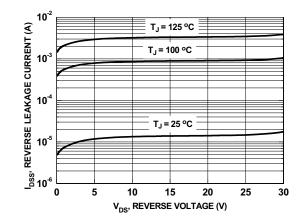
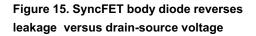


Figure 14. FDMS7670AS SyncFET body diode reverse recovery characteristic

Schottky barrier diodes exhibit significant leakage at high temperature and high reverse voltage. This will increase the power in the device.









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